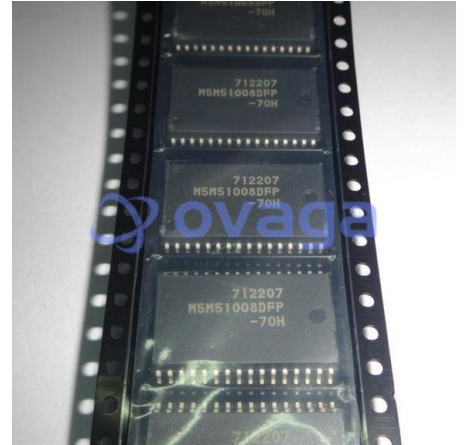


Low Power SRAM; Organization word: 128K; Organization bit: x 8; Memory capacity bit: 1M; Access time ns: 70; Supply voltage V: 4.5 to 5.5; Operating temperature °C: 0 to 70; SRAM 128Kx8-70



Images are for reference only

Manufacturers	Renesas Technology Corp
Package/Case	SOP-32
Product Type	Integrated Circuits (ICs)
RoHS	
Lifecycle	

Please submit RFQ for M5M51008DFP-70H or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

M5M51008DFP-70H is a type of dynamic random-access memory (DRAM) chip manufactured by Mitsubishi Electric Corporation.

Features

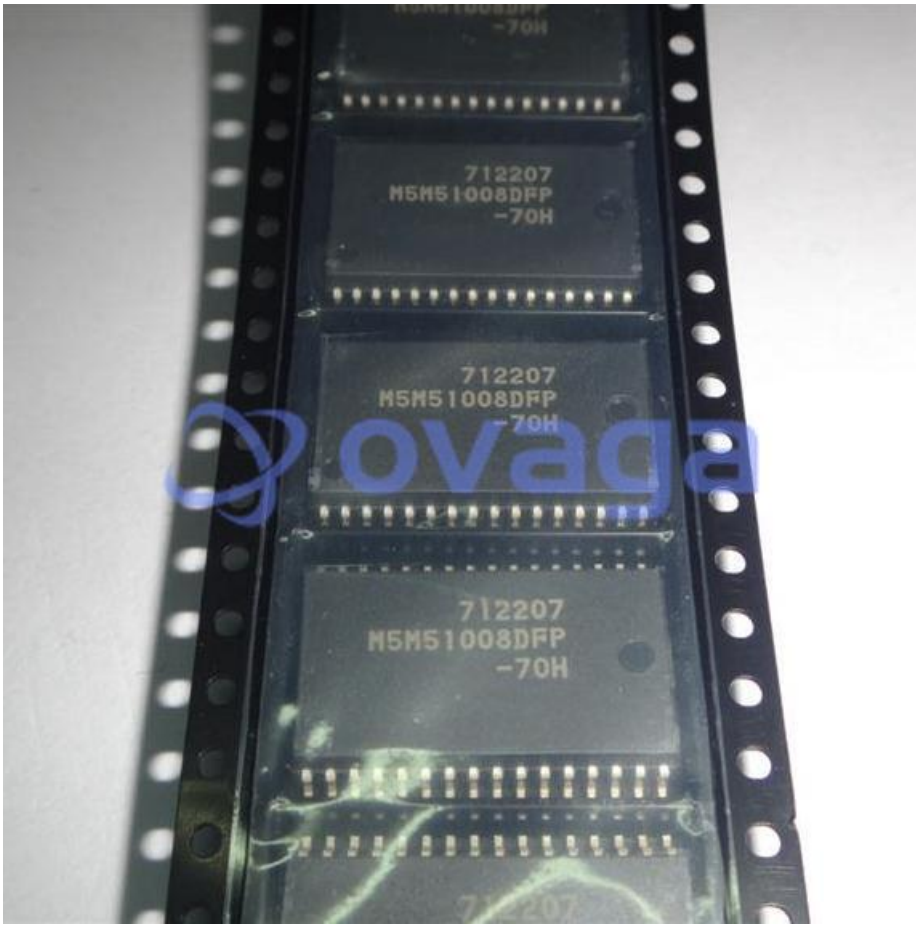
1 Megabit capacity (128K x 8)

Fast page mode access time of 70 nanoseconds

Single +5V power supply

Low standby current

JEDEC standard pin configuration





Related Products



[M51958BFP](#)

Renesas Technology Corp
SOP-20



[M51995AFP#CF0J](#)

Renesas Technology Corp
SOP-20



[M51957BFP](#)

Renesas Technology Corp
SOP-8



[M5M51008DFP-55HIBT](#)

Renesas Technology Corp
SOP-32



[M5M51008DVP-70H](#)

Renesas Technology Corp
TSOP32



[M5M5V108DVP-70H](#)

Renesas Technology Corp
TSSOP32



[M5223AFP](#)

Renesas Technology Corp
SOP-8



[M51995AP#TF0J](#)

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DIP